

L Number	Hits	Search Text	DB	Time stamp
1	84852	dielectric adj (layer or film)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2002/12/04 07:58
2	415	((dielectric adj (layer or film) ) and ((dielectric adj constant) same (convers\$3 or convert\$3))	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2002/12/04 10:23
3	299	((dielectric adj (layer or film) ) and ((dielectric adj constant) same (convers\$3 or convert\$3))) and semiconductor	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2002/12/04 08:07
4	169	((dielectric adj (layer or film) ) and ((dielectric adj constant) same (convers\$3 or convert\$3))) and semiconductor) and ("438")	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2002/12/04 08:07
5	87	(dielectric adj (layer or film) ) and ((first adj dielectric adj constant) same (second adj dielectric adj constant))	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2002/12/04 08:25
6	2	(dielectric adj (layer or film) ) and ((dielectric adj constant) same ((convers\$3 or convert\$3) adj (dielectric adj constant)))	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2002/12/04 10:24
-	394	(438/240).CCLS.	USPAT; EPO; JPO; DERWENT	2001/11/06 14:29
-	204	(438/243).CCLS.	USPAT; EPO; JPO; DERWENT	2002/05/21 14:04
-	83	(438/246).CCLS.	USPAT; EPO; JPO; DERWENT	2001/11/06 14:30
-	37	(438/247).CCLS.	USPAT; EPO; JPO; DERWENT	2001/11/06 14:30
-	218	(438/386).CCLS.	USPAT; EPO; JPO; DERWENT	2001/11/06 14:30
-	84	(438/387).CCLS.	USPAT; EPO; JPO; DERWENT	2001/11/06 14:30
-	55	(438/389).CCLS.	USPAT; EPO; JPO; DERWENT	2001/11/06 14:30
-	28	(438/390).CCLS.	USPAT; EPO; JPO; DERWENT	2001/11/09 11:10
-	107	(438/244).CCLS.	USPAT; EPO; JPO; DERWENT	2001/11/16 15:23
-	2	(cover\$3 adj3 (first adj1 area)) and (first adj1 dielectric)	USPAT	2001/11/16 15:28
-	2	((cover\$3 adj3 (first adj1 area)) and (first adj1 dielectric)) and (second adj1 dielectric)	USPAT	2001/11/16 15:29
-	155	cover\$3 adj3 (first adj1 area)	USPAT	2001/11/19 08:46
-	155	cover\$3 adj3 (first adj1 area)	USPAT	2001/11/19 08:49
-	5997	first adj1 dielectric	USPAT	2002/05/21 14:37
-	2	(first adj1 dielectric) and (cover\$3 adj3 (first adj1 area))	USPAT	2001/11/19 08:50
-	217	first adj1 dielectric adj1 constant	USPAT	2001/11/19 08:51

	0	((first adj1 dielectric adj1 constant) and (second adj1 dielectric adj1 constant)) and ((E-beams) or (I-beams) or (amine))	USPAT	2001/11/19 08:54
	0	((first adj1 dielectric adj1 constant) and (second adj1 dielectric adj1 constant)) and (E-beams)	USPAT	2001/11/19 08:54
	0	((first adj1 dielectric adj1 constant) and (second adj1 dielectric adj1 constant)) and (I-beams)	USPAT	2001/11/19 08:54
	0	((first adj1 dielectric adj1 constant) and (second adj1 dielectric adj1 constant)) and (amine)	USPAT	2001/11/19 08:54
	170	(first adj1 dielectric adj1 constant) and (second adj1 dielectric adj1 constant)	USPAT	2001/11/19 09:16
-	1557	438/240, 244, 238, 239, 243, 246, 247, 386, 389, 390, <del>USPAT</del> cls.	<del>USPAT</del> cls.	2002/12/03 14:18
-	0	438/240, 244, 238, 239, 243, 246, 247, 386, 389, 390, <del>USPAT</del> cls.	<del>USPAT</del> cls.	2002/12/03 14:21
-	1	438/240, 244, 238, 239, 243, 246, 247, 386, 389, 390, <del>USPAT</del> cls.	<del>USPAT</del> cls.	2001/11/19 11:19
-	7	438/240, 244, 238, 239, 243, 246, 247, 386, 389, 390, <del>USPAT</del> cls.	<del>USPAT</del> cls.	2001/11/19 09:19
-	0	(438/240, 244, 238, 239, 243, 246, 247, 386, 389, 390)USPATccls.	USPATccls.	2001/11/19 09:24
-	0	(438/240, 244, 238, 239, 243, 246, 247, 386, 389, 390)USPATccls.	USPATccls.	2001/11/19 09:20
-	148	438/240, 244, 238, 239, 243, 246, 247, 386, 389, 390, <del>USPAT</del> cls.	<del>USPAT</del> cls.	2001/11/19 09:20
-	118	(438/240, 244, 238, 239, 243, 246, 247, 386, 389, 390)USPATccls.	USPATccls.	2001/11/19 09:20
-	0	and (first adj1 dielectric)) and (second adj1 dielectric)		
-	0	((438/240, 244, 238, 239, 243, 246, 247, 386, 389, 390)USPAT.ccls.	USPAT.ccls.	2001/11/19 09:21
-	0	and (first adj1 dielectric)) and (second adj1 dielectric)) and (amine)		
-	0	((438/240, 244, 238, 239, 243, 246, 247, 386, 389, 390)USPAT.ccls.	USPAT.ccls.	2001/11/19 09:54
-	0	and (first adj1 dielectric)) and (second adj1 dielectric)) and (E-beams)		
-	0	((438/240, 244, 238, 239, 243, 246, 247, 386, 389, 390)USPAT.ccls.	USPAT.ccls.	2001/11/19 09:21
-	0	and (first adj1 dielectric)) and (second adj1 dielectric)) and (I-beams)		
-	0	((438/240, 244, 238, 239, 243, 246, 247, 386, 389, 390)USPAT.ccls.	USPAT.ccls.	2001/11/19 09:21
-	0	and (first adj1 dielectric)) and (second adj1 dielectric)) and (I adj1 beams)		
-	0	((438/240, 244, 238, 239, 243, 246, 247, 386, 389, 390)USPAT.ccls.	USPAT.ccls.	2001/11/19 09:21
-	0	and (first adj1 dielectric)) and (second adj1 dielectric)) and (E adj1 beams)		
-	0	((438/240, 244, 238, 239, 243, 246, 247, 386, 389, 390)USPATccls.	USPATccls.	2001/11/19 09:24
-	0	and (amine)) and (first adj1 dielectric		
-	0	438/240, 244, 238, 239, 243, 246, 247, 386, 389, 390, <del>USPAT</del> cls.	<del>USPAT</del> cls.	2002/05/21 14:38
-	0	and (first adj1 dielectric)) and (second adj1 dielectric)) and (Electron adj1		
-	0	438/240, 244, 238, 239, 243, 246, 247, 386, 389, 390, <del>USPAT</del> cls.	<del>USPAT</del> cls.	2001/11/19 09:54
-	0	and (first adj1 dielectric)) and (second adj1 dielectric)) and (Electronic adj1		
-	0	438/240, 244, 238, 239, 243, 246, 247, 386, 389, 390, <del>USPAT</del> cls.	<del>USPAT</del> cls.	2001/11/19 09:55
-	0	and (first adj1 dielectric)) and (second adj1 dielectric)) and (ions adj1 beams)		
-	0	438/240, 244, 238, 239, 243, 246, 247, 386, 389, 390, <del>USPAT</del> cls.	<del>USPAT</del> cls.	2001/11/19 09:56
-	0	and (first adj1 dielectric)) and (second adj1 dielectric)) and (hydrogen adj1		
-	0	438/240, 244, 238, 239, 243, 246, 247, 386, 389, 390, <del>USPAT</del> cls.	<del>USPAT</del> cls.	2001/11/19 09:56
-	3	and (first adj1 dielectric)) and (hydrogen adj1 silsesquioxane)		
-	1	((438/240, 244, 238, 239, 243, 246, 247, 386, 389, 390)USPAT.ccls.	USPAT.ccls.	2001/11/19 10:11
-	6	and (first adj1 dielectric)) and (oxygen adj1 plasma) ("6110842").PN.	USPAT	2001/11/19 10:11
-	6	("4764248"   "4980307"   "5672521"   "5763922"   "5834351"   "5937310").PN.	USPAT	2001/11/19 10:12

-	1	("6309922").PN.	USPAT	2001/11/19 11:31
-	2	("5652173"   "5770509").PN.	USPAT	2001/11/19 11:20
-	1	("5928960").PN.	USPAT	2001/11/19 11:31
-	281	(438/386).CCLS.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2002/05/21 14:07
-	31	(438/390).CCLS.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2002/05/21 14:07
-	59	(438/389).CCLS.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2002/05/21 14:16
-	43	(438/247).CCLS.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2002/05/21 14:35
-	96	(438/246).CCLS.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2002/05/21 14:51
-	113	(438/387).CCLS.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2002/05/21 15:04
-	164	(438/244).CCLS.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2002/05/21 15:11
-	281	(438/386).CCLS.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2002/05/22 07:40
-	273	(438/243).CCLS.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2002/05/22 08:12
-	2429	438/240,244,238,239,243,246,247,386,389,390, and (I-beams or E-beam)	USPATcls. US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2002/12/03 14:34
-	27	438/240,244,238,239,243,246,247,386,389,390, and (I-beams or E-beam)	USPATcls.	2002/12/03 14:22
-	31	438/240,244,238,239,243,246,247,386,389,390, and (I-beams or E-beam)	USPATcls. US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2002/12/03 14:22
-	2428	438/240,244,238,239,243,246,247,386,389,390,	USPATcls. US-PGPUB	2002/12/03 14:47
-	84852	dielectric adj (layer or film)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2002/12/03 14:55

-	13087	((dielectric adj (layer or film)) and (convers\$3 or convert\$3))	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/12/03 14:56
-	7979	((dielectric adj (layer or film)) and (convers\$3 or convert\$3)) and semiconductor	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/12/03 14:56
-	3203	((dielectric adj (layer or film)) and (convers\$3 or convert\$3)) and semiconductor and ("438")	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/12/03 14:56
-	909	((dielectric adj (layer or film)) and (convers\$3 or convert\$3)) and semiconductor and ("438") and (dielectric adj constant)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/12/03 14:56
-	84852	dielectric adj (layer or film)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/12/04 07:57
-	13087	((dielectric adj (layer or film)) and (convers\$3 or convert\$3))	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/12/03 14:56
-	7979	((dielectric adj (layer or film)) and (convers\$3 or convert\$3)) and semiconductor	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/12/03 14:56
-	3203	((dielectric adj (layer or film)) and (convers\$3 or convert\$3)) and semiconductor and ("438")	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/12/03 14:56
-	909	((dielectric adj (layer or film)) and (convers\$3 or convert\$3)) and semiconductor and ("438") and (dielectric adj constant)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/12/03 14:57